

1N5186 thru 1N5188, 1N5190

FAST RECOVERY DIODE

TECHNICAL DATA DATA SHEET 124, REV A.1

AVAILABLE AS

1N

JAN, JANTX, JANTXV

JANS

JAN EQUIVALENT*

SJ49XX*, SX49XX*, SV49XX*

SS49XX*

Fast Recovery Rectifiers

Qualified per MIL-PRF-19500/424

DESCRIPTION:

This voidless hermetically sealed fast recovery rectifier diode series is military qualified per MIL-PRF-19500/424 and is targeted for space, commercial and military aircraft, military vehicles, shipboard markets and all high reliability applications.

✓ FEATURES / BENEFITS

- ✓ Hermetic, non-cavity glass package
- ✓ Category I Metallurgically bonded
- ✓ All devices are 100% hot solder dipped
- ✓ JAN/ JANTX/JANTXV available per MIL-PRF-19500/424
- √ "JANS Plus" removes atvoical/out of family V_E

MAXIMUM RATINGS

- ✓ Operating and Storage Temperature: -65°C to +175°C
- ✓ Solder temperature: 260 °C for 10s (max)
- ✓ Thermal Resistance: 20 °C (junction to lead)



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ELECTRICAL CHARACTERISTICS

MAX. RATINGS / ELECTRICAL CHARACTERISTICS All ratings are at $T_A = 25^{\circ}$ C unless otherwise specified.

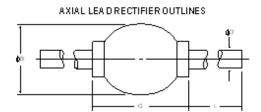
RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV) 1N5186 1N5187 1N5188 1N5190	-	-	-	100 200 400 600	Vdc
Average DC Output Current (I _o)	$T_A = +25$ °C $T_A = +150$ °C	-	-	3.0 0.7	Amps
Peak Single Cycle Surge Current (I _{fsm})	t _p = 8.3 ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	80	Amps(pk)
Operating and Storage Temp. $(T_{op} \& T_{stg})$	-	-65	-	+175	°C
Maximum Forward Voltage (V _f)	I _f = 9A (300 μsec pulse, duty cycle < 2%)	.9	-	1.5	Volts
Maximum Instantaneous Reverse Current At Rated (PIV)	T _A = 25° C T _A = 100° C	-	-	2.0 100	μAmps
Reverse Recovery Time (t _{rr}) 1N5186 1N5187 1N5188 1N5190	I _f = 0.5A, I _r = 1.0A, I _{rr} = 0.25A	-	-	150 200 250 400	nsec
Thermal Resistance (θ _{JL})	d = 0.375"	-	-	20	° C/W

^{*}Sensitron **space equivalent diodes** are manufactured and screened to MIL-PRF-19500 flow and guidelines starting from wafer fabrication through assembly and testing using our internal specification.

SENSITRON SEMICONDUCTOR

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PACKAGE DIMENSIONS (inches/mm)



Note: Cathode side of device is indicated by a dark band marked on body.

PART ORDERING INFORMATION

The following part numbers can be screened and tested to the military screening flow. The parts are marked in accordance with the testing performed, example:

Sensitron Screening Level	*Part Number Leaded Package (example for 1N5186)		
1N	1N5186		
JAN	JAN1N5186		
SJ	SJ5186		
JANTX	JANTX1N5186		
SX	SX5186		
JANTXV	JANTXV1N5186		
sv	SV5186		

^{*}Parts can also be ordered Tape & Reel

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